Mirror MEMS Variable Optical Attenuator

Product Introduction

Mirror MEMS Attenuators are based on a micro-electro-mechanical system (MEMS) technology. The MEMS attenuators design achieves highly repeatable optical attenuation over C and/or L band through an electrically movable mirror on silicon.

Features

- Low insertion loss
- Compact size
- Available in both normally open and normally closed states
- Excellent reliability

Applications

- Power equalization in multi-channel, optically amplified networks
- Gain-tilt control in erbium doped fiber amplifiers (EDFAs)
- Dynamic Gain/Channel Equalizers (DGE/DCE) in DWDM/CWDM networks, For ROADM power balance
- Photoreceiver trimming
- Receiver protection/switch during transmitter turn-ons

Standards

- Telcordia GR-1221-CORE
- RoHS

Specifications

Parameter		Unit	Value		
			Min	typical	Max
Wavelength		nm	C Band 1528-1565		L Band 1570-1607
Insertion Loss		dB			0.8
Return Loss		dB	40		
Attenuation Range		dB	30		
PDL	0~15	dB			0.3
	15~20				0.5
TDL	0~15	dB		0.5	0.6
	15~20			0.8	1
Response time		ms			10
Polarization Mode Dispersion		ps			0.1
Maximum Optical Power		mW			300
Repeatability		dB			0.1
Operation Temperature		℃	-5~+65		
Package		mm	Φ5.35x26		

Note: 1. All insertion loss don't include connector loss.

Ordering Information

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Operation Voltage：5:5V、15:15V

Connector：FC,SC,LC,MU/PC,UPC,APC,00：no connector

NA：the connectors are different between input ports and output ports.

Fiber length：1:1m、customer specify

Fiber Dia.：025: Φ0.25mm、09：Φ0.9mm

Attenuation Range.：15: 15dB、20:20dB、25:25dB、30:30dB

Operating Wavelength：C:C Bband、L:L Bband、C/L:C+L band

Type：D:Dark、B:Bright